

**CBRHDSH1-100**  
**SURFACE MOUNT**  
**HIGH DENSITY**  
**1 AMP SILICON**  
**SCHOTTKY BRIDGE RECTIFIER**



[www.centrasemi.com](http://www.centrasemi.com)

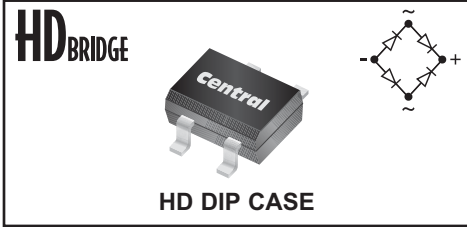
**DESCRIPTION:**

The CENTRAL SEMICONDUCTOR CBRHDSH1-100 is a full wave bridge rectifier in a durable epoxy surface mount molded case, designed for low voltage full wave rectification applications. The molding compound used in this device has UL flammability classification 94V-O.

**MARKING CODE: CSH110**

**FEATURES:**

- Low Leakage Current (40nA TYP @  $V_{RRM}$ )
- Low Forward Voltage Drop Schottky Diodes
- High 1.0A Current Rating



**MAXIMUM RATINGS:** ( $T_A=25^\circ\text{C}$  unless otherwise noted)

	<b>SYMBOL</b>		<b>UNITS</b>
Peak Repetitive Reverse Voltage	$V_{RRM}$	100	V
DC Blocking Voltage	$V_R$	100	V
RMS Reverse Voltage	$V_{R(RMS)}$	71	V
Average Forward Current	$I_O$	1.0	A
Peak Forward Surge Current	$I_{FSM}$	20	A
Power Dissipation	$P_D$	1.2	W
Operating Junction Temperature	$T_J$	-50 to +125	$^\circ\text{C}$
Storage Temperature	$T_{stg}$	-55 to +150	$^\circ\text{C}$
Thermal Resistance	$\Theta_{JA}$	85	$^\circ\text{C/W}$

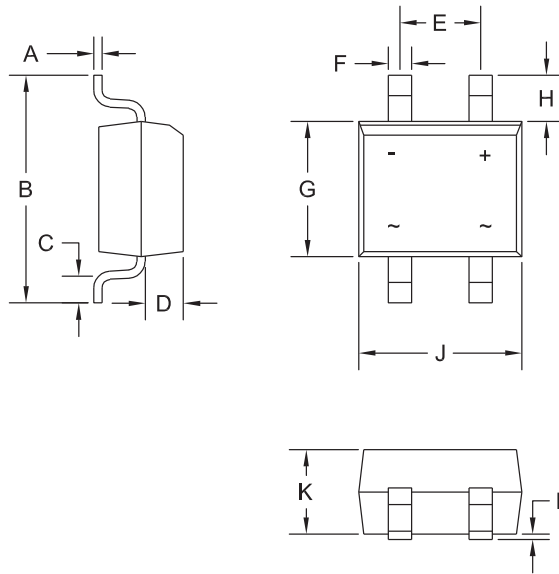
**ELECTRICAL CHARACTERISTICS PER DIODE:** ( $T_A=25^\circ\text{C}$  unless otherwise noted)

<b>SYMBOL</b>	<b>TEST CONDITIONS</b>	<b>MIN</b>	<b>TYP</b>	<b>MAX</b>	<b>UNITS</b>
$I_R$	$V_R=100\text{V}$		0.04	10	$\mu\text{A}$
$I_R$	$V_R=100\text{V}, T_A=50^\circ\text{C}$			1.0	mA
$I_R$	$V_R=100\text{V}, T_A=100^\circ\text{C}$			20	mA
$BV_R$	$I_R=150\mu\text{A}$	100			V
$V_F$	$I_F=500\text{mA}$		615	700	mV
$V_F$	$I_F=1.0\text{A}$		690	750	mV
$C_J$	$V_R=4.0\text{V}, f=1.0\text{MHz}$		230		pF

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**HD DIP CASE - MECHANICAL OUTLINE**



R2

<b>DIMENSIONS</b>				
SYMBOL	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.006	0.014	0.15	0.35
B	-	0.275	-	7.00
C	0.027	0.043	0.70	1.10
D	0.035	0.051	0.90	1.30
E	0.090	0.106	2.30	2.70
F	0.019	0.031	0.50	0.80
G	0.150	0.165	3.80	4.20
H	0.051	0.067	1.30	1.70
J	0.177	0.193	4.50	4.90
K	0.090	0.106	2.30	2.70
L	0.000	0.008	0.00	0.20

HD DIP (REV: R2)

**MARKING CODE: CSH110**

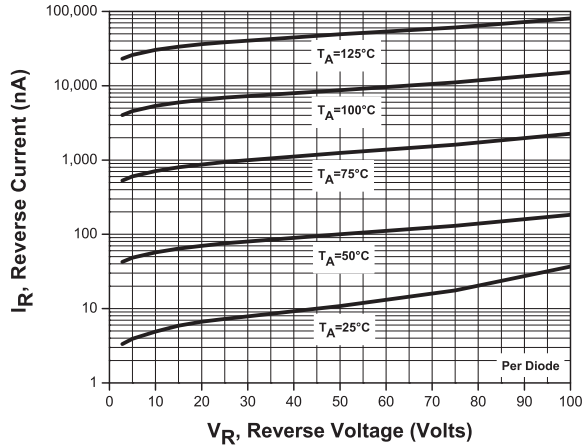
R6 (22-May 2012)

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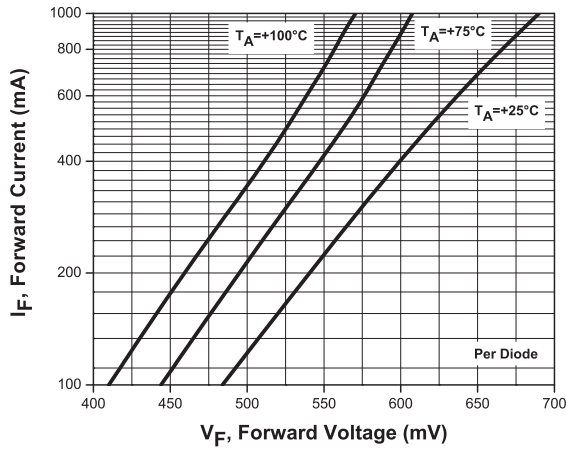


**TYPICAL ELECTRICAL CHARACTERISTICS**

**Typical Leakage Current**



**Typical Forward Voltage**



R6 (22-May 2012)